

## TLC5925 Low-Power 16-Channel Constant-Current LED Sink Driver

### 1 Features

- 16 Constant-Current Output Channels
- Constant Output Current Invariant to Load Voltage Change
- Excellent Output Current Accuracy:
  - Between Channels:  $< \pm 4\%$  (Max)
  - Between ICs:  $< \pm 6\%$  (Max)
- Constant Output Current Range: 3 mA to 45 mA
- Output Current Adjusted By External Resistor
- Fast Response of Output Current,  $\overline{OE}$  (Min): 100 ns
- 30-MHz Clock Frequency
- Schmitt-Trigger Inputs
- 3.3-V to 5-V Supply Voltage
- Thermal Shutdown for Overtemperature Protection
- ESD Performance: 1-kV HBM

### 2 Applications

- Gaming Machine and Entertainment
- General LED Applications
- LED Display Systems
- Signs LED Lighting
- White Goods

### 3 Description

The TLC5925 is designed for LED displays and LED lighting applications. The TLC5925 contains a 16-bit shift register and data latches, which convert serial input data into parallel output format. At the TLC5925 output stage, 16 regulated-current ports provide uniform and constant current for driving LEDs within a wide range of VF variations. Used in system design for LED display applications (such as, LED panels), the TLC5925 provides great flexibility and device performance. Users can adjust the output current from 3 mA to 45 mA through an external resistor,  $R_{ext}$ , which gives flexibility in controlling the light intensity of LEDs. TLC5925 is designed for up to 17 V at the output port. The high clock frequency, 30 MHz, also satisfies the system requirements of high-volume data transmission.

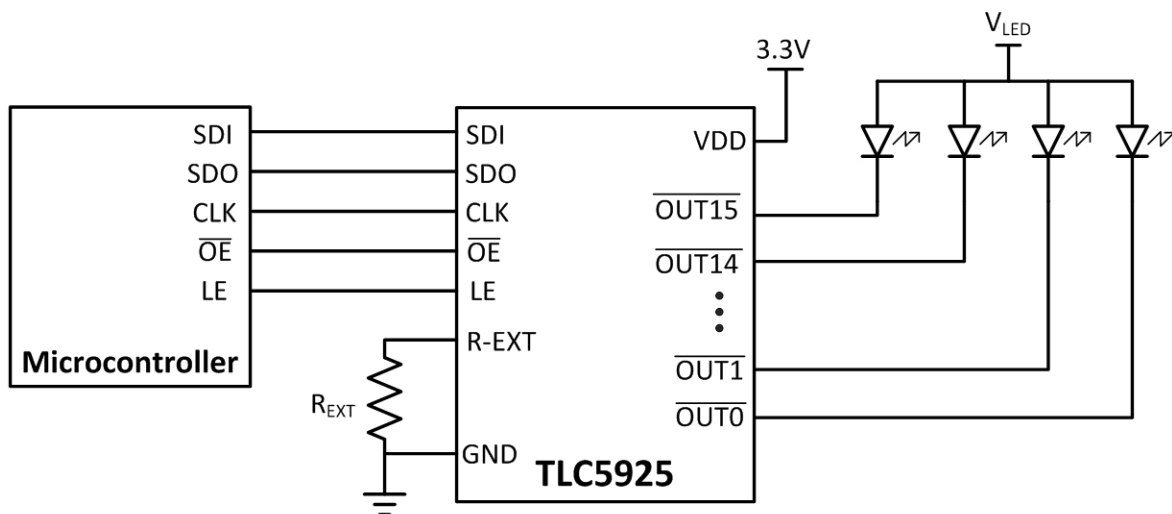
The serial data is transferred into TLC5925 via SDI, shifted in the shift register, and transferred out via SDO. LE can latch the serial data in the shift register to the output latch.  $\overline{OE}$  enables the output drivers to sink current.

Device Information (1)

| PART NUMBER | PACKAGE    | BODY SIZE (NOM)    |
|-------------|------------|--------------------|
| TLC5925     | SSOP (24)  | 8.65 mm x 3.90 mm  |
|             | SOIC (24)  | 15.40 mm x 7.50 mm |
|             | TSSOP (24) | 7.80 mm x 4.40 mm  |

(1) For all available packages, see the orderable addendum at the end of the datasheet.

### Typical Application



## Table of Contents

|   |           |  |           |
|---|-----------|--|-----------|
| <b>1 Features</b> .....                                       | <b>1</b>  | <b>8 Detailed Description</b> .....                              | <b>12</b> |
| <b>2 Applications</b> .....                                   | <b>1</b>  | 8.1 Overview .....   | 12        |
| <b>3 Description</b> .....                                    | <b>1</b>  | 8.2 Functional Block Diagram .....                               | 12        |
| <b>4 Revision History</b> .....                               | <b>2</b>  | 8.3 Feature Description .....                                    | 12        |
| <b>5 Pin Configuration and Functions</b> .....                | <b>3</b>  | 8.4 Device Functional Modes .....                                | 13        |
| <b>6 Specifications</b> .....                                 | <b>4</b>  | <b>9 Application and Implementation</b> .....                    | <b>14</b> |
| 6.1 Absolute Maximum Ratings .....                            | 4         | 9.1 Application Information .....                                | 14        |
| 6.2 ESD Ratings .....   | 4         | 9.2 Typical Application .....                                    | 15        |
| 6.3 Recommended Operating Conditions .....                    | 4         | <b>10 Power Supply Recommendations</b> .....                     | <b>16</b> |
| 6.4 Thermal Information .....                                 | 5         | <b>11 Layout</b> .....   | <b>16</b> |
| 6.5 Electrical Characteristics: $V_{DD} = 3\text{ V}$ .....   | 5         | 11.1 Layout Guidelines .....                                     | 16        |
| 6.6 Electrical Characteristics: $V_{DD} = 5.5\text{ V}$ ..... | 6         | 11.2 Layout Example .....  | 17        |
| 6.7 Power Dissipation and Thermal Impedance .....             | 6         | <b>12 Device and Documentation Support</b> .....                 | <b>18</b> |
| 6.8 Timing Requirements .....                                 | 7         | 12.1 Community Resources .....                                   | 18        |
| 6.9 Switching Characteristics: $V_{DD} = 3\text{ V}$ .....    | 7         | 12.2 Trademarks .....  | 18        |
| 6.10 Switching Characteristics: $V_{DD} = 5.5\text{ V}$ ..... | 8         | 12.3 Electrostatic Discharge Caution .....                       | 18        |
| 6.11 Typical Characteristics .....                            | 9         | 12.4 Glossary .....  | 18        |
| <b>7 Parameter Measurement Information</b> .....              | <b>10</b> | <b>13 Mechanical, Packaging, and Orderable Information</b> ..... | <b>18</b> |

## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

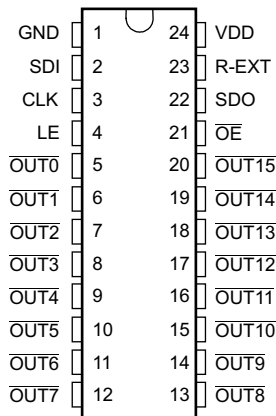
### Changes from Revision A (March 2013) to Revision B

Page

- Added *Pin Configuration and Functions* section, *ESD Ratings* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section ..... **1**

## 5 Pin Configuration and Functions

**DBQ, DW, or PWP Package  
24-Pin SSOP, SOIC, or TSSOP  
Top View**



**Pin Functions**

| PIN                |     | I/O | DESCRIPTION  |
|--------------------|-----|-----|--|
| NAME               | NO. |     |  |
| CLK                | 3   | I   | Clock input for data shift on rising edge  |
| GND                | 1   | —   | Ground for control logic and current sink  |
| LE                 | 4   | I   | Data strobe input<br>Serial data is transferred to the respective latch when LE is high.<br>The data is latched when LE goes low.<br>LE has an internal pull-down resistor.  |
| $\overline{OE}$    | 21  | I   | Output enable<br>When $\overline{OE}$ is active (low), the output drivers are enabled.<br>When $\overline{OE}$ is high, all output drivers are turned OFF (blanked).<br>$\overline{OE}$ has an internal pullup resistor. |
| $\overline{OUT0}$  | 5   | O   | Constant-current outputs   |
| $\overline{OUT1}$  | 6   |     |  |
| $\overline{OUT2}$  | 7   |     |  |
| $\overline{OUT3}$  | 8   |     |  |
| $\overline{OUT4}$  | 9   |     |  |
| $\overline{OUT5}$  | 10  |     |  |
| $\overline{OUT6}$  | 11  |     |  |
| $\overline{OUT7}$  | 12  |     |  |
| $\overline{OUT8}$  | 13  |     |  |
| $\overline{OUT9}$  | 14  |     |  |
| $\overline{OUT10}$ | 15  |     |  |
| $\overline{OUT11}$ | 16  |     |  |
| $\overline{OUT12}$ | 17  |     |  |
| $\overline{OUT13}$ | 18  |     |  |
| $\overline{OUT14}$ | 19  |     |  |
| $\overline{OUT15}$ | 20  |     |  |
| R-EXT              | 23  | I   | Input used to connect an external resistor ( $R_{ext}$ ) for setting output currents   |
| SDI                | 2   | I   | Serial-data input to the Shift register  |
| SDO                | 22  | O   | Serial-data output to the following SDI of next driver IC or to the microcontroller  |
| VDD                | 24  | I   | Supply voltage   |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup>

|                  |                                      | MIN  | MAX                   | UNIT |
|------------------|--------------------------------------|------|-----------------------|------|
| V <sub>DD</sub>  | Supply voltage                       | 0    | 7                     | V    |
| V <sub>I</sub>   | Input voltage                        | -0.4 | V <sub>DD</sub> + 0.4 | V    |
| V <sub>O</sub>   | Output voltage                       | -0.5 | 20                    | V    |
| I <sub>OUT</sub> | Output current                       |      | 45                    | mA   |
| I <sub>GND</sub> | GND terminal current                 |      | 750                   | mA   |
| T <sub>A</sub>   | Free-air operating temperature range | -40  | 125                   | °C   |
| T <sub>J</sub>   | Operating junction temperature range | -40  | 150                   | °C   |
| T <sub>stg</sub> | Storage temperature range            | -55  | 150                   | °C   |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings

|                    |                         | VALUE  | UNIT  |
|--------------------|-------------------------|--|-------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±1000 |
|                    |                         | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±500  |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.  
 (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                 |                           | MIN   | MAX                    | UNIT                  |
|-----------------|---------------------------|---|------------------------|-----------------------|
| V <sub>DD</sub> | Supply voltage            | 3   | 5.5                    | V                     |
| V <sub>O</sub>  | Output voltage            | $\overline{\text{OUT}}_0$ to $\overline{\text{OUT}}_{15}$ |                        | 17                    |
| I <sub>O</sub>  | Output current            | DC test circuit   | V <sub>O</sub> ≥ 0.6 V | 3                     |
|                 |                           |   | V <sub>O</sub> ≥ 1 V   | 45                    |
| I <sub>OH</sub> | High-level output current | SDO   |                        | -1                    |
| I <sub>OL</sub> | Low-level output current  | SDO   |                        | 1                     |
| V <sub>IH</sub> | High-level input voltage  | CLK, $\overline{\text{OE}}$ , LE, and SDI                 |                        | 0.7 × V <sub>DD</sub> |
| V <sub>IL</sub> | Low-level input voltage   | CLK, $\overline{\text{OE}}$ , LE, and SDI                 |                        | GND                   |
| t <sub>R</sub>  | Rise Time                 | CLK   |                        | 500                   |
| t <sub>F</sub>  | Fall Time                 | CLK   |                        | 500                   |

## 6.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |  |  | TLC5925       |              |               | UNIT |
|-------------------------------|--|--|---------------|--------------|---------------|------|
|                               |  |  | DBQ<br>(SSOP) | DW<br>(SOIC) | PW<br>(TSSOP) |      |
|                               |  |  | 24 PINS       | 24 PINS      | 24 PINS       |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | Mounted on JEDEC 1-layer board (JESD 51-3), No airflow | 99.8          | 80.5         | 118.8         | °C/W |
|                               |  | Mounted on JEDEC 4-layer board (JESD 51-7), No airflow | 61            | 45.5         | 87.9          | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    |  | 52.9          | 45.0         | 44.9          | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         |  | 41.5          | 44.8         | 52.9          | °C/W |
| Ψ <sub>JT</sub>               | Junction-to-top characterization parameter   |  | 16.4          | 21.7         | 6.7           | °C/W |
| Ψ <sub>JB</sub>               | Junction-to-board characterization parameter |  | 41.2          | 44.4         | 52.5          | °C/W |
| R <sub>θJC(bot)</sub>         | Junction-to-case (bottom) thermal resistance |  | n/a           | n/a          | n/a           | °C/W |

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

## 6.5 Electrical Characteristics: V<sub>DD</sub> = 3 V

V<sub>DD</sub> = 3 V, T<sub>J</sub> = –40°C to 125°C (unless otherwise noted)

| PARAMETER                            |   | TEST CONDITIONS   | MIN                    | TYP | MAX                   | UNIT |
|--------------------------------------|---|---|------------------------|-----|-----------------------|------|
| V <sub>DD</sub>                      | Input voltage                               |   | 3                      |     | 5.5                   | V    |
| V <sub>O</sub>                       | Output voltage                              |   |                        |     | 17                    | V    |
| I <sub>O</sub>                       | Output current                              | V <sub>O</sub> ≥ 0.6 V  | 3                      |     |                       | mA   |
|                                      |   | V <sub>O</sub> ≥ 1 V  |                        |     | 45                    |      |
| I <sub>OH</sub>                      | High-level output current, source           |   | -1                     |     |                       | mA   |
| I <sub>OL</sub>                      | Low-level output current, sink              |   | 1                      |     |                       |      |
| V <sub>IH</sub>                      | High-level input voltage                    |   | 0.7 × V <sub>DD</sub>  |     | V <sub>DD</sub>       | V    |
| V <sub>IL</sub>                      | Low-level input voltage                     |   | GND                    |     | 0.3 × V <sub>DD</sub> |      |
| I <sub>leak</sub>                    | Output leakage current                      | V <sub>OH</sub> = 17 V  | T <sub>J</sub> = 25°C  |     | 0.5                   | μA   |
|                                      |   |   | T <sub>J</sub> = 125°C |     | 2                     |      |
| V <sub>OH</sub>                      | High-level output voltage                   | SDO, I <sub>OL</sub> = –1 mA  | V <sub>DD</sub> – 0.4  |     |                       | V    |
| V <sub>OL</sub>                      | Low-level output voltage                    | SDO, I <sub>OH</sub> = 1 mA   |                        |     | 0.4                   | V    |
| I <sub>O(1)</sub>                    | Output current 1                            | V <sub>OUT</sub> = 0.6 V, R <sub>ext</sub> = 1680 Ω   | 13                     |     |                       | mA   |
|                                      | Output current error, die-die               | I <sub>OL</sub> = 13 mA, V <sub>O</sub> = 0.6 V, R <sub>ext</sub> = 1680 Ω, T <sub>J</sub> = 25°C | ±3%                    |     | ±6%                   |      |
|                                      | Output current error, channel-to-channel    | I <sub>OL</sub> = 13 mA, V <sub>O</sub> = 0.6 V, R <sub>ext</sub> = 1680 Ω, T <sub>J</sub> = 25°C | ±1.5%                  |     | ±4%                   |      |
| I <sub>O(2)</sub>                    | Output current 2                            | V <sub>O</sub> = 0.8 V, R <sub>ext</sub> = 840 Ω  | 26                     |     |                       | mA   |
|                                      | Output current error, die-die               | I <sub>OL</sub> = 26 mA, V <sub>O</sub> = 0.8 V, R <sub>ext</sub> = 840 Ω, T <sub>J</sub> = 25°C  | ±3%                    |     | ±6%                   |      |
|                                      | Output current error, channel-to-channel    | I <sub>OL</sub> = 26 mA, V <sub>O</sub> = 0.8 V, R <sub>ext</sub> = 840 Ω, T <sub>J</sub> = 25°C  | ±1.5%                  |     | ±4%                   |      |
| I <sub>OUT</sub> vs V <sub>OUT</sub> | Output current vs output voltage regulation | V <sub>O</sub> = 1 V to 3 V, I <sub>O</sub> = 13 mA   | ±0.1                   |     |                       | %V   |
|                                      |   | V <sub>DD</sub> = 3.0 V to 5.5 V, I <sub>O</sub> = 13 mA to 45 mA                                 | ±1                     |     |                       |      |
|                                      | Pullup resistance                           | $\overline{OE}$   | 500                    |     |                       | kΩ   |
|                                      | Pulldown resistance                         | LE  | 500                    |     |                       | kΩ   |
| T <sub>sd</sub>                      | Overtemperature shutdown <sup>(1)</sup>     |   | 150                    | 175 | 200                   | °C   |
| T <sub>hys</sub>                     | Restart temperature hysteresis              |   | 15                     |     |                       | °C   |
| I <sub>DD</sub>                      | Supply current                              | R <sub>ext</sub> = Open   | 7                      |     | 10                    | mA   |
|                                      |   | R <sub>ext</sub> = 1680 Ω   | 9                      |     | 12                    |      |
|                                      |   | R <sub>ext</sub> = 840 Ω  | 11                     |     | 13                    |      |
| C <sub>IN</sub>                      | Input capacitance                           | V <sub>I</sub> = V <sub>DD</sub> or GND, CLK, SDI, SDO, $\overline{OE}$                           |                        |     | 10                    | pF   |

(1) Specified by design

## 6.6 Electrical Characteristics: $V_{DD} = 5.5\text{ V}$

 $V_{DD} = 5.5\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $125^\circ\text{C}$  (unless otherwise noted)

| PARAMETER              |   | TEST CONDITIONS  | MIN                       | TYP         | MAX                 | UNIT             |
|------------------------|---|--|---------------------------|-------------|---------------------|------------------|
| $V_{DD}$               | Input voltage                               |  | 3                         |             | 5.5                 | V                |
| $V_O$                  | Output voltage                              |  |                           |             | 17                  | V                |
| $I_O$                  | Output current                              | $V_O \geq 0.6\text{ V}$  | 3                         |             |                     | mA               |
|                        |   | $V_O \geq 1\text{ V}$  |                           |             | 45                  |                  |
| $I_{OH}$               | High-level output current, source           |  | -1                        |             |                     | mA               |
| $I_{OL}$               | Low-level output current, sink              |  | 1                         |             |                     |                  |
| $V_{IH}$               | High-level input voltage                    |  | $0.7 \times V_{DD}$       |             | $V_{DD}$            | V                |
| $V_{IL}$               | Low-level input voltage                     |  | GND                       |             | $0.3 \times V_{DD}$ |                  |
| $I_{leak}$             | Output leakage current                      | $V_{OH} = 17\text{ V}$   | $T_J = 25^\circ\text{C}$  |             | 0.5                 | $\mu\text{A}$    |
|                        |   |  | $T_J = 125^\circ\text{C}$ |             | 2                   |                  |
| $V_{OH}$               | High-level output voltage                   | SDO, $I_{OL} = -1\text{ mA}$   | $V_{DD} - 0.4$            |             |                     | V                |
| $V_{OL}$               | Low-level output voltage                    | SDO, $I_{OH} = 1\text{ mA}$  |                           |             | 0.4                 | V                |
| $I_{O(1)}$             | Output current 1                            | $V_{OUT} = 0.6\text{ V}$ , $R_{ext} = 1680\ \Omega$  |                           | 13          |                     | mA               |
|                        | Output current error, die-die               | $I_{OL} = 13\text{ mA}$ , $V_O = 0.6\text{ V}$ , $R_{ext} = 1680\ \Omega$ , $T_J = 25^\circ\text{C}$ |                           | $\pm 3\%$   | $\pm 6\%$           |                  |
|                        | Output current error, channel-to-channel    | $I_{OL} = 13\text{ mA}$ , $V_O = 0.6\text{ V}$ , $R_{ext} = 1680\ \Omega$ , $T_J = 25^\circ\text{C}$ |                           | $\pm 1.5\%$ | $\pm 4\%$           |                  |
| $I_{O(2)}$             | Output current 2                            | $V_O = 0.8\text{ V}$ , $R_{ext} = 840\ \Omega$   |                           | 26          |                     | mA               |
|                        | Output current error, die-die               | $I_{OL} = 26\text{ mA}$ , $V_O = 0.8\text{ V}$ , $R_{ext} = 840\ \Omega$ , $T_J = 25^\circ\text{C}$  |                           | $\pm 3\%$   | $\pm 6\%$           |                  |
|                        | Output current error, channel-to-channel    | $I_{OL} = 26\text{ mA}$ , $V_O = 0.8\text{ V}$ , $R_{ext} = 840\ \Omega$ , $T_J = 25^\circ\text{C}$  |                           | $\pm 1.5\%$ | $\pm 4\%$           |                  |
| $I_{OUT}$ vs $V_{OUT}$ | Output current vs output voltage regulation | $V_O = 1\text{ V}$ to $3\text{ V}$ , $I_O = 26\text{ mA}$  |                           | $\pm 0.1$   |                     | %V               |
|                        |   | $V_{DD} = 3.0\text{ V}$ to $5.5\text{ V}$ , $I_O = 13\text{ mA}$ to $45\text{ mA}$                   |                           | $\pm 1$     |                     |                  |
|                        | Pullup resistance                           | $\overline{OE}$  |                           | 500         |                     | k $\Omega$       |
|                        | Pulldown resistance                         | LE   |                           | 500         |                     | k $\Omega$       |
| $T_{sd}$               | Overtemperature shutdown <sup>(1)</sup>     |  | 150                       | 175         | 200                 | $^\circ\text{C}$ |
| $T_{hys}$              | Restart temperature hysteresis              |  |                           | 15          |                     | $^\circ\text{C}$ |
| $I_{DD}$               | Supply current                              | $R_{ext} = \text{Open}$  |                           | 9           | 11                  | mA               |
|                        |   | $R_{ext} = 1680\ \Omega$   |                           | 12          | 14                  |                  |
|                        |   | $R_{ext} = 840\ \Omega$  |                           | 14          | 16                  |                  |
| $C_{IN}$               | Input capacitance                           | $V_I = V_{DD}$ or GND, CLK, SDI, SDO, $\overline{OE}$  |                           |             | 10                  | pF               |

(1) Specified by design

## 6.7 Power Dissipation and Thermal Impedance

|       |                   |   | MIN         | MAX | UNIT |
|-------|-------------------|---|-------------|-----|------|
| $P_D$ | Power dissipation | Mounted on JEDEC 4-layer board (JESD 51-7),<br>No airflow, $T_A = 25^\circ\text{C}$ , $T_J = 125^\circ\text{C}$ | DBQ package | 1.6 | W    |
|       |                   |   | DW package  | 2.2 |      |
|       |                   |   | PW package  | 1.1 |      |

## 6.8 Timing Requirements

 $V_{DD} = 3\text{ V to }5.5\text{ V}$  (unless otherwise noted)

|              |                                    | MIN | MAX | UNIT |
|--------------|------------------------------------|-----|-----|------|
| $t_{w(L)}$   | LE pulse duration                  | 15  |     | ns   |
| $t_{w(CLK)}$ | CLK pulse duration                 | 15  |     | ns   |
| $t_{w(OE)}$  | $\overline{OE}$ pulse duration     | 300 |     | ns   |
| $t_{su(D)}$  | Setup time for SDI                 | 3   |     | ns   |
| $t_{h(D)}$   | Hold time for SDI                  | 2   |     | ns   |
| $t_{su(L)}$  | Setup time for LE                  | 5   |     | ns   |
| $t_{h(L)}$   | Hold time for LE                   | 5   |     | ns   |
| $f_{CLK}$    | Clock frequency, Cascade operation |     | 30  | MHz  |

## 6.9 Switching Characteristics: $V_{DD} = 3\text{ V}$

 $V_{DD} = 3\text{ V}$ ,  $T_J = -40^\circ\text{C to }125^\circ\text{C}$  (unless otherwise noted)

| PARAMETER    | TEST CONDITIONS  | MIN | TYP | MAX | UNIT |
|--------------|--|-----|-----|-----|------|
| $t_{PLH1}$   | Low-to-high propagation delay time, CLK to $\overline{OUTn}$             | 30  | 45  | 60  | ns   |
| $t_{PLH2}$   | Low-to-high propagation delay time, LE to $\overline{OUTn}$              | 30  | 45  | 60  | ns   |
| $t_{PLH3}$   | Low-to-high propagation delay time, $\overline{OE}$ to $\overline{OUTn}$ | 30  | 45  | 60  | ns   |
| $t_{PLH4}$   | Low-to-high propagation delay time, CLK to SDO                           |     | 30  | 40  | ns   |
| $t_{PHL1}$   | High-to-low propagation delay time, CLK to $\overline{OUTn}$             | 40  | 65  | 100 | ns   |
| $t_{PHL2}$   | High-to-low propagation delay time, LE to $\overline{OUTn}$              | 40  | 65  | 100 | ns   |
| $t_{PHL3}$   | High-to-low propagation delay time, $\overline{OE}$ to $\overline{OUTn}$ | 40  | 65  | 100 | ns   |
| $t_{PHL4}$   | High-to-low propagation delay time, CLK to SDO                           |     | 30  | 40  | ns   |
| $t_{w(CLK)}$ | Pulse duration, CLK  | 15  |     |     | ns   |
| $t_{w(L)}$   | Pulse duration, LE   | 15  |     |     | ns   |
| $t_{w(OE)}$  | Pulse duration, $\overline{OE}$  | 300 |     |     | ns   |
| $t_{h(D)}$   | Hold time, SDI   | 2   |     |     | ns   |
| $t_{su(D)}$  | Setup time, SDI  | 3   |     |     | ns   |
| $t_{h(L)}$   | Hold time, LE  | 5   |     |     | ns   |
| $t_{su(L)}$  | Setup time, LE   | 5   |     |     | ns   |
| $t_r$        | Rise time, CLK <sup>(1)</sup>  |     |     | 500 | ns   |
| $t_f$        | Fall time, CLK <sup>(1)</sup>  |     |     | 500 | ns   |
| $t_{or}$     | Rise time, outputs (off)   | 35  | 50  | 70  | ns   |
| $t_{of}$     | Rise time, outputs (on)  | 15  | 50  | 120 | ns   |
| $f_{CLK}$    | Clock frequency  |     |     | 30  | MHz  |

$V_{IH} = V_{DD}$ ,  $V_{IL} = \text{GND}$ ,  
 $R_{ext} = 840\ \Omega$ ,  $V_L = 4\text{ V}$ ,  
 $R_L = 88\ \Omega$ ,  $C_L = 10\text{ pF}$

(1) If the devices are connected in cascade and  $t_r$  or  $t_f$  is large, it may be critical to achieve the timing required for data transfer between two cascaded devices.

## 6.10 Switching Characteristics: $V_{DD} = 5.5\text{ V}$

 $V_{DD} = 5.5\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $125^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                 |  | TEST CONDITIONS   | MIN               | TYP | MAX | UNIT |
|---------------------------|--|---|-------------------|-----|-----|------|
| $t_{PLH1}$                | Low-to-high propagation delay time, CLK to $\overline{\text{OUTn}}$                    | $V_{IH} = V_{DD}$ , $V_{IL} = \text{GND}$ ,<br>$R_{\text{ext}} = 840\ \Omega$ , $V_L = 4\text{ V}$ ,<br>$R_L = 88\ \Omega$ , $C_L = 10\text{ pF}$ | 20                | 35  | 55  | ns   |
| $t_{PLH2}$                | Low-to-high propagation delay time, LE to $\overline{\text{OUTn}}$                     |   | 20                | 35  | 55  | ns   |
| $t_{PLH3}$                | Low-to-high propagation delay time, $\overline{\text{OE}}$ to $\overline{\text{OUTn}}$ |   | 20                | 35  | 55  | ns   |
| $t_{PLH4}$                | Low-to-high propagation delay time, CLK to SDO   |   |                   | 20  | 30  | ns   |
| $t_{PHL1}$                | High-to-low propagation delay time, CLK to $\overline{\text{OUTn}}$                    |   | 15                | 28  | 42  | ns   |
| $t_{PHL2}$                | High-to-low propagation delay time, LE to $\overline{\text{OUTn}}$                     |   | 15                | 28  | 42  | ns   |
| $t_{PHL3}$                | High-to-low propagation delay time, $\overline{\text{OE}}$ to $\overline{\text{OUTn}}$ |   | 15                | 28  | 42  | ns   |
| $t_{PHL4}$                | High-to-low propagation delay time, CLK to SDO   |   |                   | 20  | 30  | ns   |
| $t_{w(\text{CLK})}$       | Pulse duration, CLK  |   | 10                |     |     | ns   |
| $t_{w(\text{L})}$         | Pulse duration LE  |   | 10                |     |     | ns   |
| $t_{w(\text{OE})}$        | Pulse duration, $\overline{\text{OE}}$   |   | 200               |     |     | ns   |
| $t_{h(\text{D})}$         | Hold time, SDI   |   | 2                 |     |     | ns   |
| $t_{\text{su}(\text{D})}$ | Setup time, SDI  |   | 3                 |     |     | ns   |
| $t_{h(\text{L})}$         | Hold time, LE  |   | 5                 |     |     | ns   |
| $t_{\text{su}(\text{L})}$ | Setup time, LE   |   | 5                 |     |     | ns   |
| $t_r$                     | Rise time, CLK <sup>(1)</sup>  |   |                   |     | 500 | ns   |
| $t_f$                     | Fall time, CLK <sup>(1)</sup>  |   |                   |     | 500 | ns   |
| $t_{\text{or}}$           | Rise time, outputs (off)   |   | 25                | 45  | 65  | ns   |
| $t_{\text{of}}$           | Rise time, outputs (on)  |   | 7                 | 12  | 20  | ns   |
| $f_{\text{CLK}}$          | Clock frequency  |   | Cascade operation |     |     | 30   |

(1) If the devices are connected in cascade and  $t_r$  or  $t_f$  is large, it may be critical to achieve the timing required for data transfer between two cascaded devices.



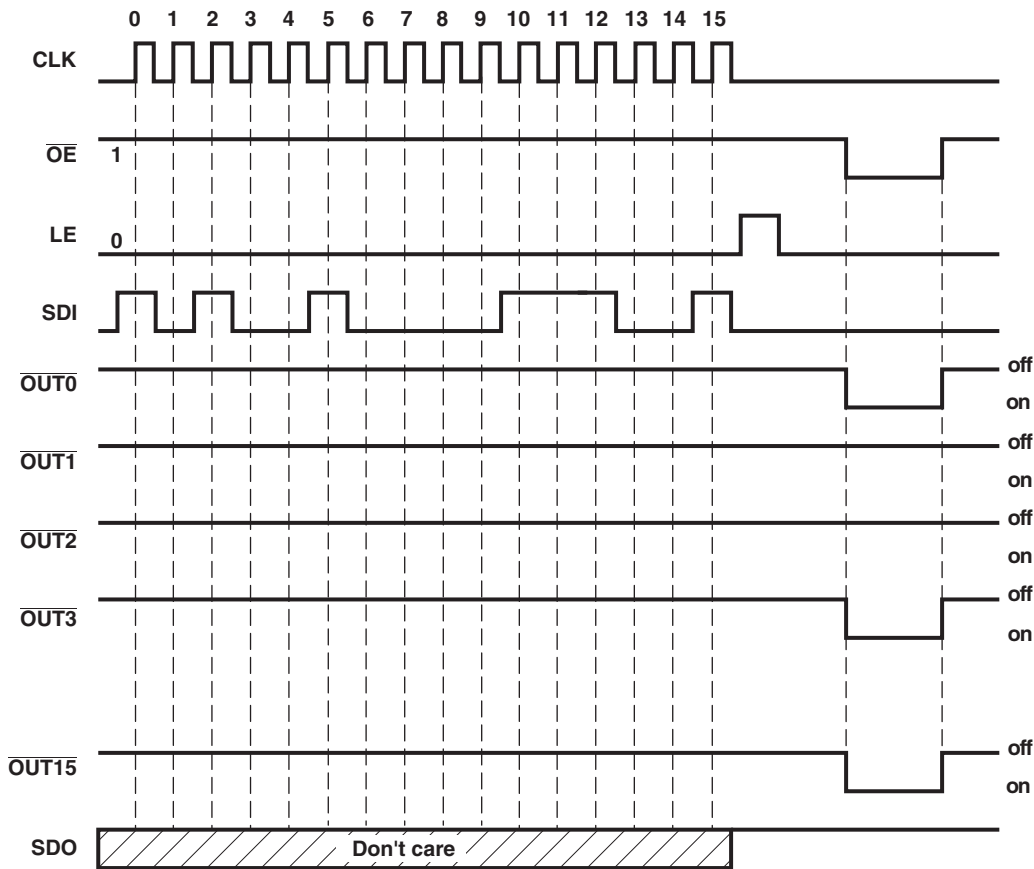


Figure 1. Timing Diagram

### 6.11 Typical Characteristics

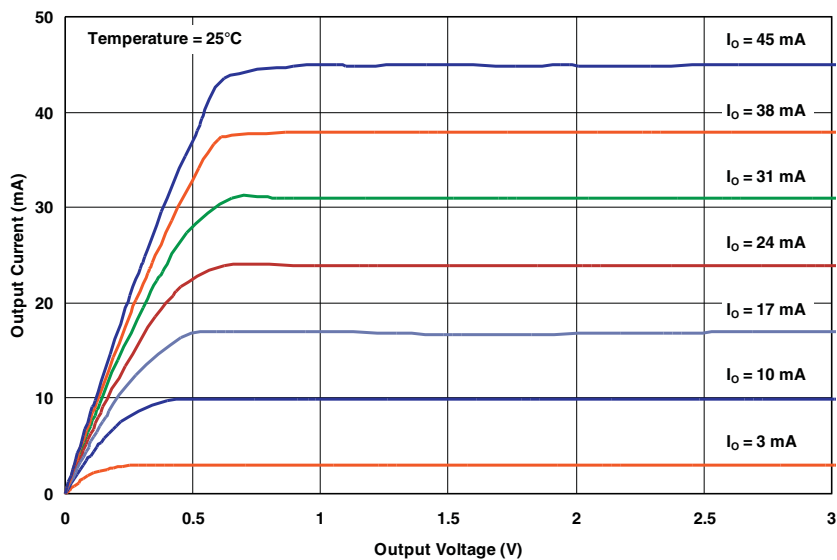
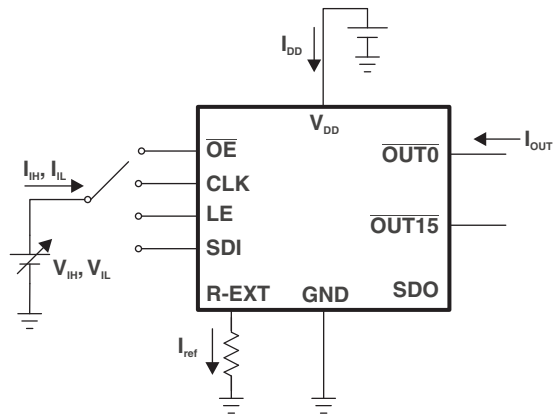
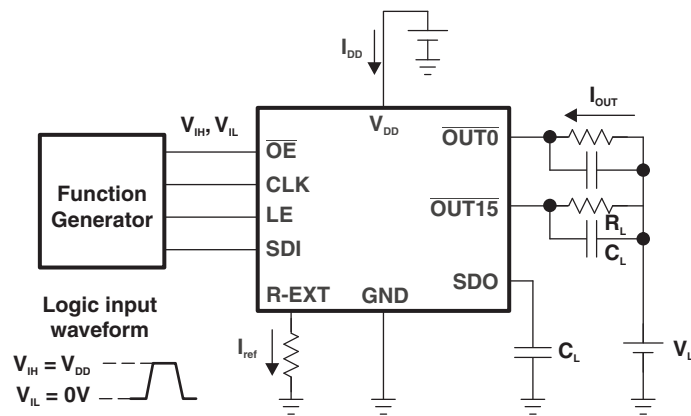


Figure 2. Output Current vs Output Voltage

## 7 Parameter Measurement Information



**Figure 3. Test Circuit for Electrical Characteristics**



**Figure 4. Test Circuit for Switching Characteristics**

Parameter Measurement Information (continued)

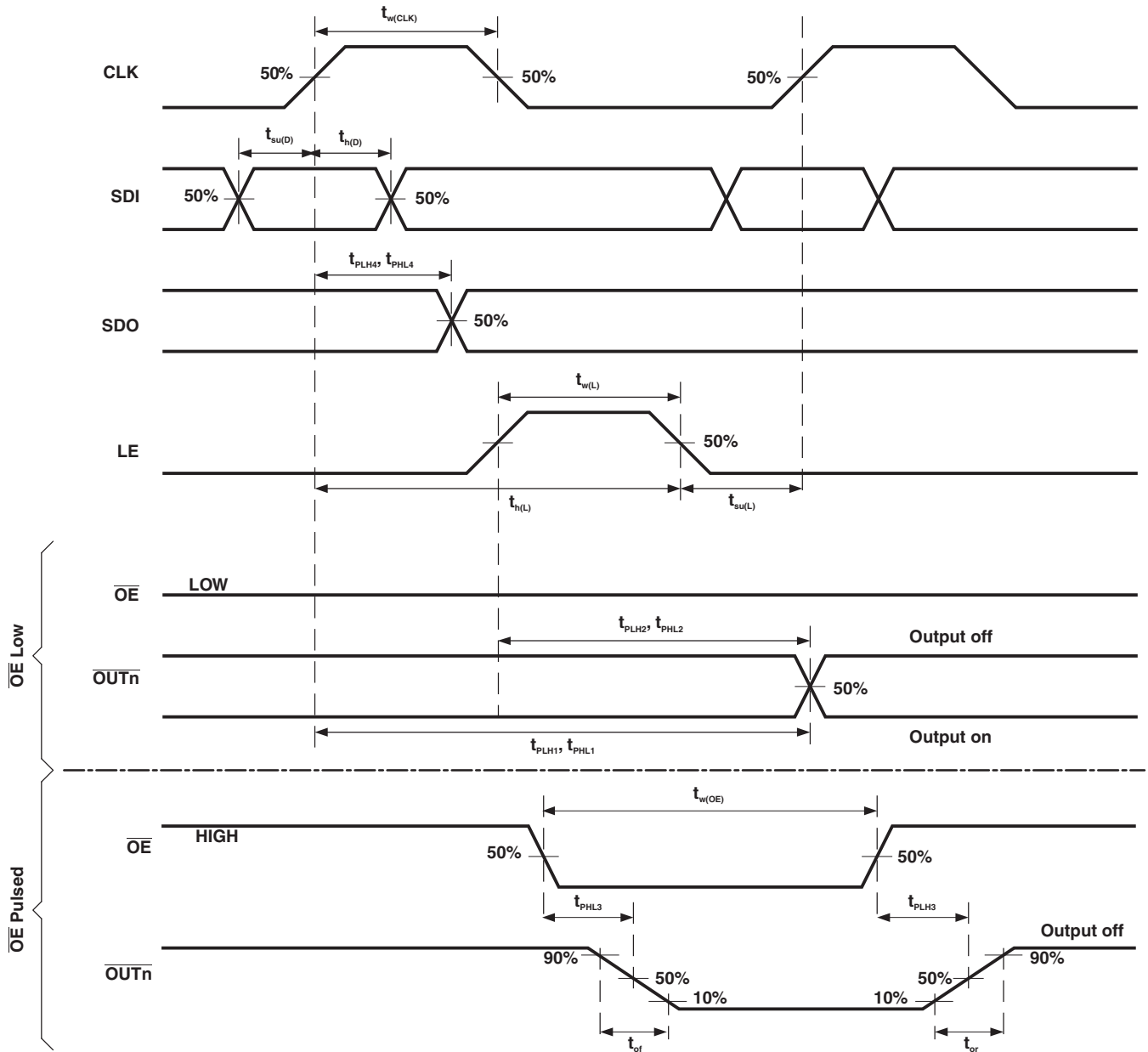


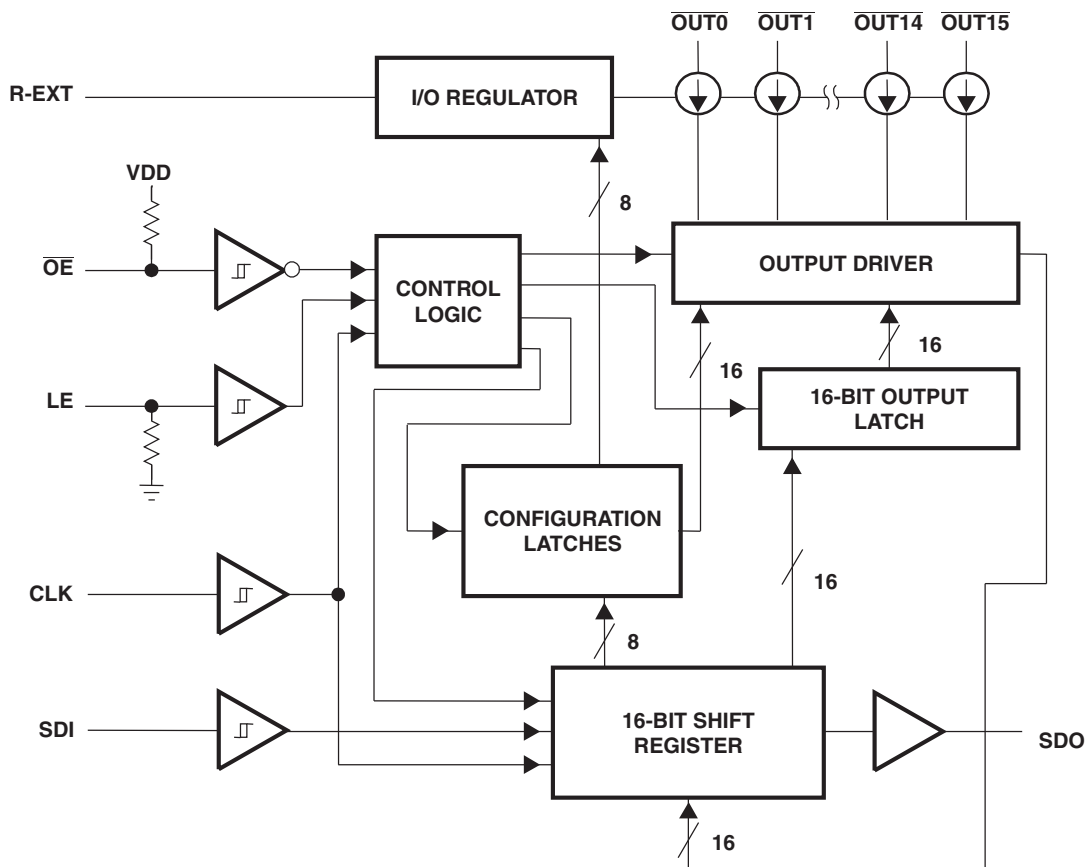
Figure 5. Normal Mode Timing Waveforms

## 8 Detailed Description

### 8.1 Overview

The TLC5925 is a 16-channel LED driver designed for LED displays and LED lighting applications. The TLC5925 contains a 16-bit shift register and data latches, which convert serial input data into parallel output format. At the TLC5925 output stage, 16 regulated-current ports provide uniform and constant current for driving LEDs within a wide range of  $V_F$  variations. Used in system design for LED display applications (for example, LED panels), the TLC5925 provides great flexibility and device performance. Users can adjust the output current from 3 mA to 45 mA through an external resistor, REXT, which gives flexibility in controlling the light intensity of LEDs. TLC59025 is designed for up to 17 V at the output port. The high clock frequency, 30 MHz, also satisfies the system requirements of high-volume data transmission.

### 8.2 Functional Block Diagram



### 8.3 Feature Description

#### 8.3.1 Constant Current

In LED display applications, TLC5925 provides nearly no current variations from channel to channel and from IC to IC. While  $I_{OUT} \leq 45$  mA, the maximum current skew between channels is less than  $\pm 5\%$  and between ICs is less than  $\pm 6\%$ .

## 8.4 Device Functional Modes

The table below lists the functional modes for the TLC5925.

**Table 1. Truth Table in Normal Operation**

| CLK | LE | $\overline{OE}$ | SDI    | $\overline{OUT0} \dots \overline{OUT15} \dots \overline{OUT15}$ | SDO     |
|-----|----|-----------------|--------|---|---------|
| ↑   | H  | L               | Dn     | Dn...Dn – 7...Dn – 15   | Dn – 15 |
| ↑   | L  | L               | Dn + 1 | No change   | Dn – 14 |
| ↑   | H  | L               | Dn + 2 | Dn + 2...Dn – 5...Dn – 13                                       | Dn – 13 |
| ↓   | X  | L               | Dn + 3 | Dn + 2...Dn – 5...Dn – 13                                       | Dn – 13 |
| ↓   | X  | H               | Dn + 3 | off   | Dn – 13 |

## 9 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

#### 9.1.1 Turning on the LEDs

To turn on an LED connected to one of the outputs of the device, the output must be pulled low. To do this, the SDI signal must let the device know which outputs should be activated. Using the rising edge of CLK, the logic level of the SDI signal latches the desired state of each output into the shift register. Once this is complete, the LE signal must be toggled from low to high then back to low. Once /OE is pulled down, the corresponding outputs will be pulled low and the LEDs will be turned on. The below diagram shows outputs 0, 3, 4, 5, 10, 13, and 15 being activated.

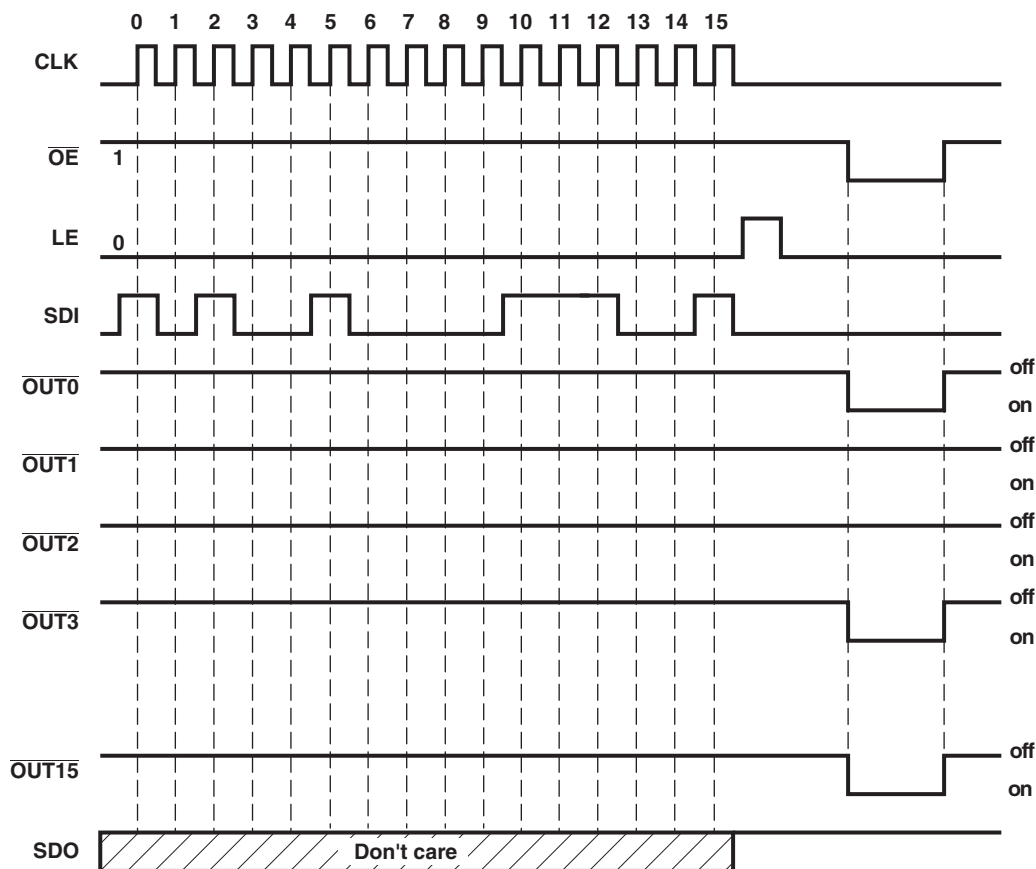


Figure 6. Timing Diagram

## Application Information (continued)

### 9.1.2 Propagation Delay Times

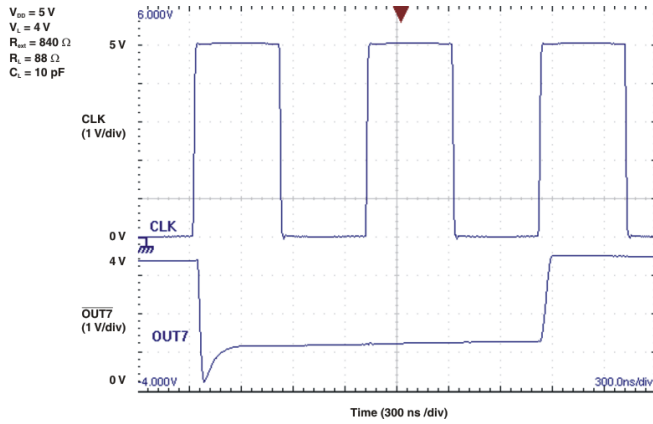


Figure 7. CLK to  $\overline{\text{OUT7}}$

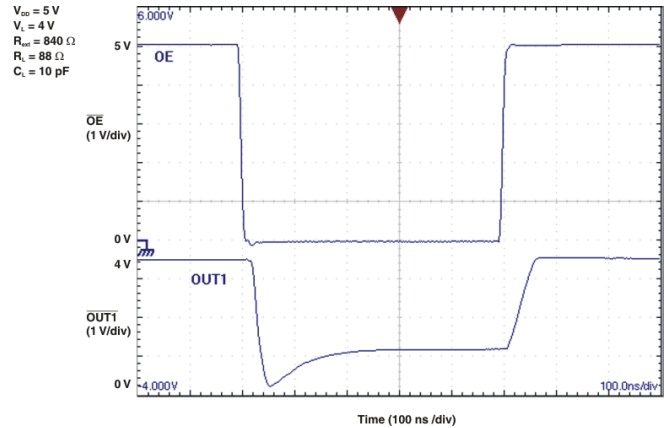


Figure 8.  $\overline{\text{OE}}$  to  $\overline{\text{OUT1}}$

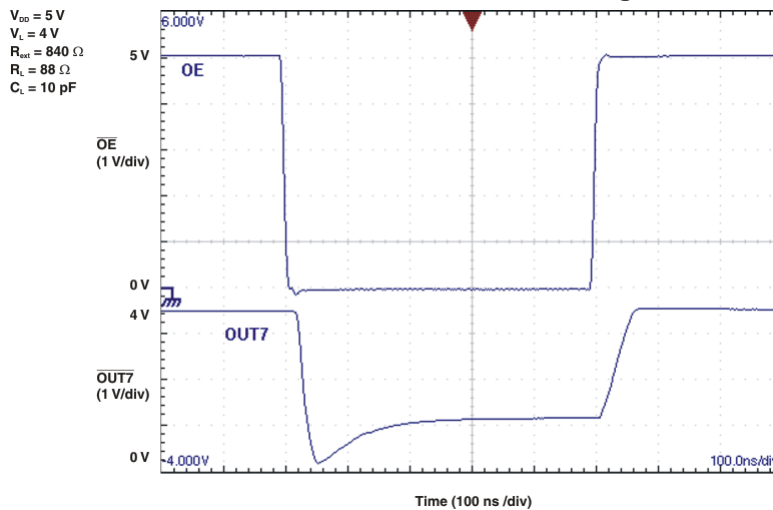
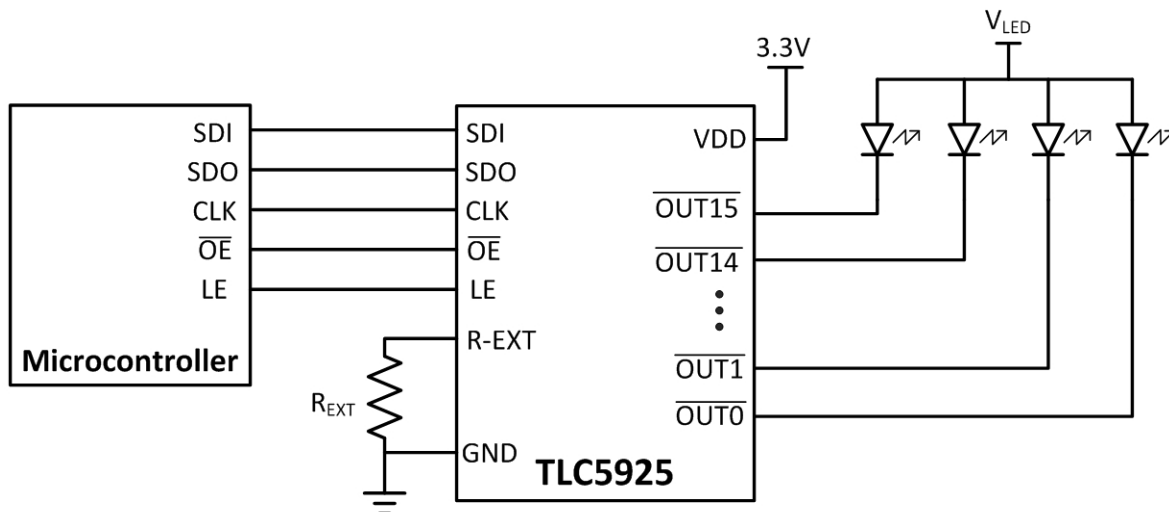


Figure 9.  $\overline{\text{OE}}$  to  $\overline{\text{OUT7}}$

## 9.2 Typical Application



## Typical Application (continued)

### 9.2.1 Design Requirements

For the following design procedure, the input voltage (VDD) is between 3 V and 5.5 V.

### 9.2.2 Detailed Design Procedure

#### 9.2.2.1 Adjusting Output Current

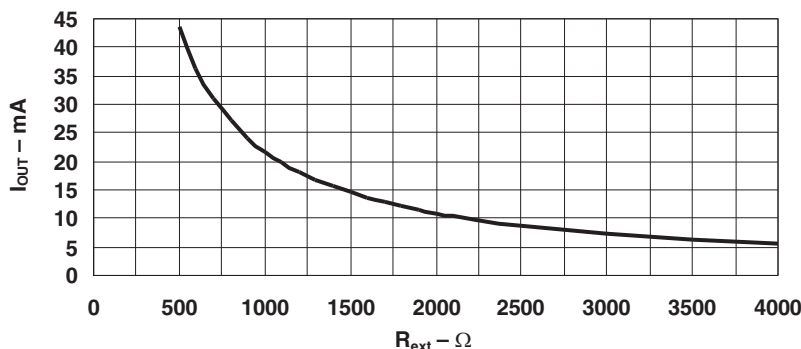
TLC5925 sets  $I_{OUT}$  based on the external resistor  $R_{ext}$ . Users can follow the below formulas to calculate the target output current  $I_{OUT,target}$  in the saturation region:

$I_{OUT,target} = (1.21 \text{ V} / R_{ext}) \times 18$ , where  $R_{ext}$  is the external resistance connected between R-EXT and GND.

Therefore, the default current is approximately 26 mA at 840  $\Omega$  and 13 mA at 1680  $\Omega$ .

### 9.2.3 Application Curve

The default relationship after power on between  $I_{OUT,target}$  and  $R_{ext}$  is shown in [Figure 10](#).



**Figure 10. Default Relationship Curve Between  $I_{OUT,target}$  and  $R_{ext}$  After Power Up**

## 10 Power Supply Recommendations

The TLC5925 is designed to operate with a VDD range between 3 V and 5.5 V.

## 11 Layout

### 11.1 Layout Guidelines

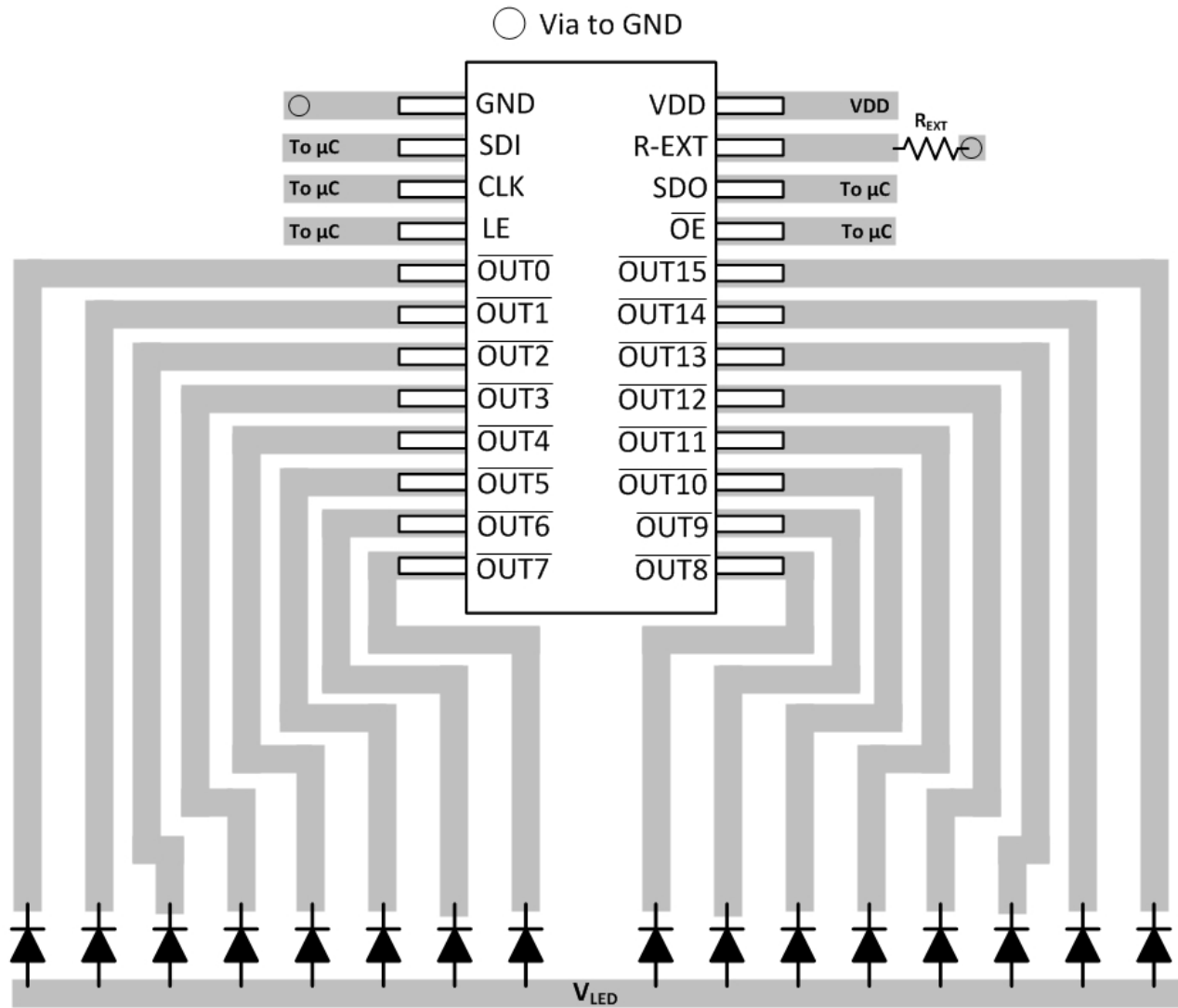
The SDI, CLK, SDO, LE, and OE signals should all be kept from potential noise sources.

All traces carrying power through the LEDs should be wide enough to handle necessary currents.

All LED current passes through the device and into the ground node. There must be a strong connection between the device ground and the circuit board ground.



## 11.2 Layout Example



## 12 Device and Documentation Support

### 12.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 12.2 Trademarks

E2E is a trademark of Texas Instruments.  
All other trademarks are the property of their respective owners.

### 12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 12.4 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| TLC5925IDBQR     | ACTIVE        | SSOP         | DBQ                | 24   | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-2-260C-1 YEAR  | -40 to 125   | TLC5925I                | <a href="#">Samples</a> |
| TLC5925IDWR      | ACTIVE        | SOIC         | DW                 | 24   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 125   | TLC5925I                | <a href="#">Samples</a> |
| TLC5925IDWRG4    | ACTIVE        | SOIC         | DW                 | 24   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 125   | TLC5925I                | <a href="#">Samples</a> |
| TLC5925IPWR      | ACTIVE        | TSSOP        | PW                 | 24   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 125   | Y5925                   | <a href="#">Samples</a> |
| TLC5925IPWRG4    | ACTIVE        | TSSOP        | PW                 | 24   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 125   | Y5925                   | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION



### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TLC5925IDBQR | SSOP         | DBQ             | 24   | 2500 | 330.0              | 16.4               | 6.5     | 9.0     | 2.1     | 8.0     | 16.0   | Q1            |
| TLC5925IDWR  | SOIC         | DW              | 24   | 2000 | 330.0              | 24.4               | 10.75   | 15.7    | 2.7     | 12.0    | 24.0   | Q1            |
| TLC5925IPWR  | TSSOP        | PW              | 24   | 2000 | 330.0              | 16.4               | 6.95    | 8.3     | 1.6     | 8.0     | 16.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TLC5925IDBQR | SSOP         | DBQ             | 24   | 2500 | 367.0       | 367.0      | 38.0        |
| TLC5925IDWR  | SOIC         | DW              | 24   | 2000 | 350.0       | 350.0      | 43.0        |
| TLC5925IPWR  | TSSOP        | PW              | 24   | 2000 | 367.0       | 367.0      | 38.0        |



PW0024A



**PACKAGE OUTLINE**  
**TSSOP - 1.2 mm max height**

SMALL OUTLINE PACKAGE



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

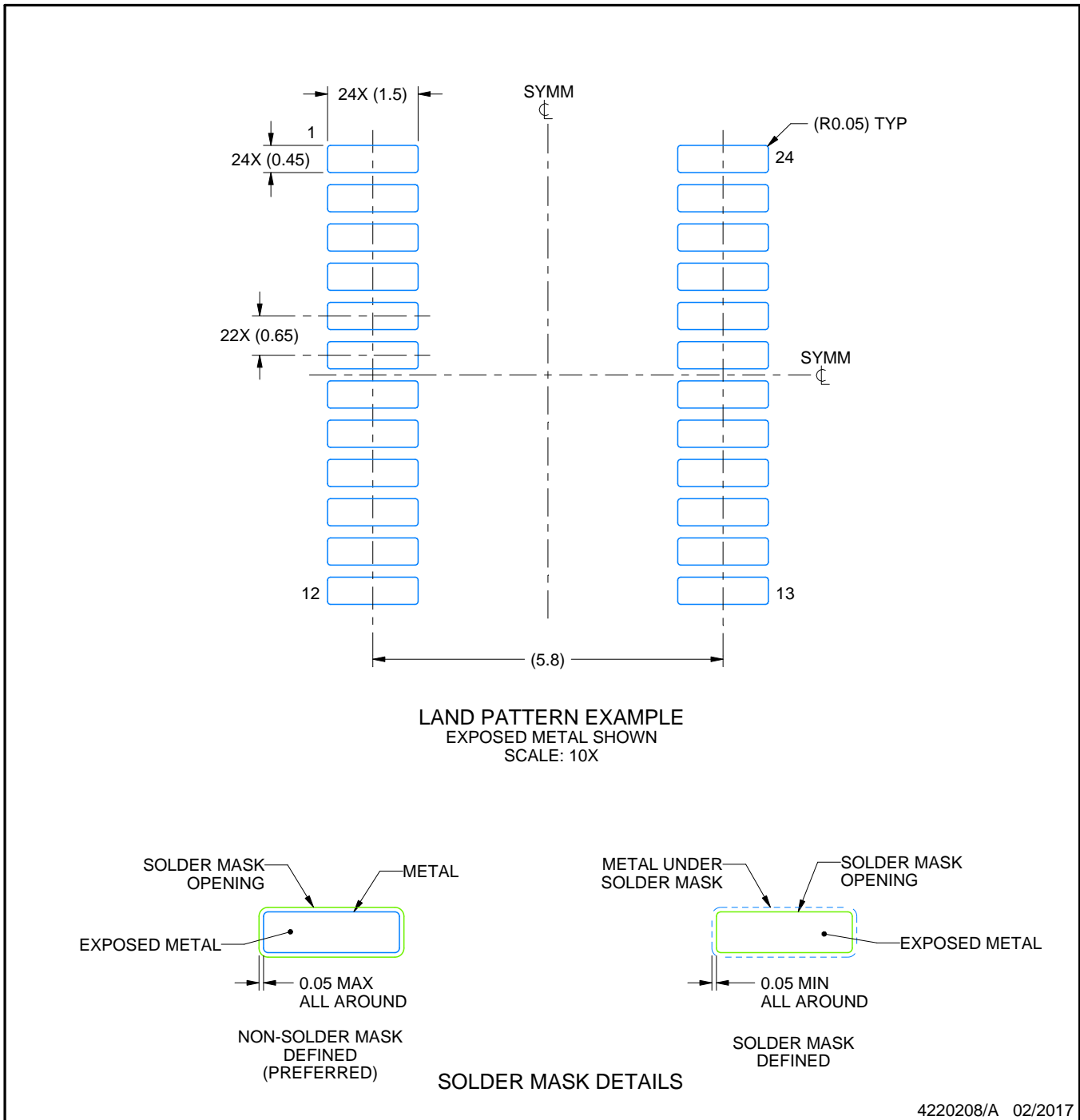


# EXAMPLE BOARD LAYOUT

PW0024A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0024A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DW (R-PDSO-G24)

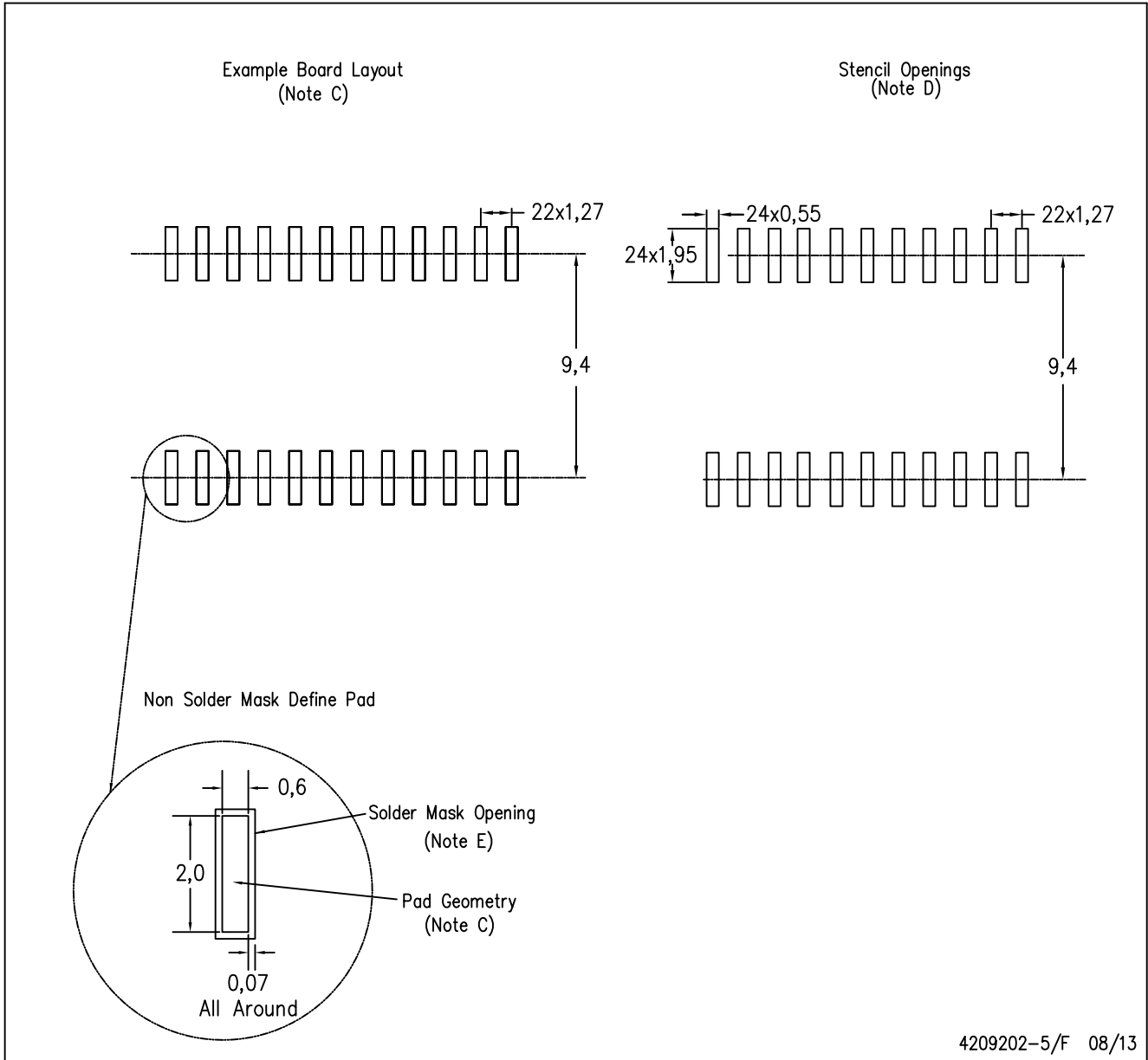
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
  - D. Falls within JEDEC MS-013 variation AD.

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



4209202-5/F 08/13

- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Refer to IPC7351 for alternate board design.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale ([www.ti.com/legal/termsofsale.html](http://www.ti.com/legal/termsofsale.html)) or other applicable terms available either on [ti.com](http://ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265  
Copyright © 2019, Texas Instruments Incorporated